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## PH 8252 PHYSICS FOR INFORMATION SCIENCE

LTPC3003

## **UNIT I ELECTRICAL PROPERTIES OF MATERIALS 9**

Classical free electron theory - Expression for electrical conductivity – Thermal conductivity, expression - Wiedemann-Franz law – Success and failures - electrons in metals – Particle in a three-dimensional box – degenerate states – Fermi- Dirac statistics – Density of energy states – Electron in periodic potential – Energy bands in solids – tight binding approximation – Electron effective mass – concept of hole.

## UNIT II SEMICONDUCTOR PHYSICS 9

Intrinsic Semiconductors – Energy band diagram – direct and indirect band gap semiconductors – Carrier concentration in intrinsic semiconductors – extrinsic semiconductors – Carrier concentration in N-type & P-type semiconductors – Variation of carrier concentration with temperature – variation of Fermi level with temperature and impurity concentration – Carrier transport in Semiconductor: random motion, drift, mobility and diffusion – Hall effect and devices – Ohmic contacts – Schottky diode.

#### **UNIT III MAGNETIC PROPERTIES OF MATERIALS 9**

Magnetic dipole moment – atomic magnetic moments- magnetic permeability and susceptibility - Magnetic material classification: diamagnetism – paramagnetism – ferromagnetism – anti ferromagnetism – ferrimagnetism – Ferromagnetism: origin and exchange interaction- saturation magnetization and Curie temperature – Domain Theory- M versus H behaviour – Hard and soft magnetic materials – examples and uses-– Magnetic principle in computer data storage – Magnetic hard disc (GMR sensor).

## UNIT IV OPTICAL PROPERTIES OF MATERIALS 9

Classification of optical materials – carrier generation and recombination processes – Absorption emission and scattering of light in metals, insulators and semiconductors (concepts only) – photo current in a P-N diode – solar cell - LED – Organic LED – Laser diodes – Optical data storage techniques.

#### UNIT V NANO DEVICES 9

Electron density in bulk material – Size dependence of Fermi energy – Quantum confinement – Quantum structures – Density of states in quantum well, quantum wire and quantum dot structure - Band gap of nanomaterials – Tunnelling: single electron phenomena and single electron transistor – Quantum dot laser. Conductivity of metallic nanowires – Ballistic transport – Quantum resistance and conductance – Carbon nanotubes: Properties and applications.

## TEXT BOOKS:

1. Jasprit Singh, —Semiconductor Devices: Basic Principlesll, Wiley 2012.

2. Kasap, S.O. —Principles of Electronic Materials and DevicesII, McGraw-Hill Education, 2007.

3. Kittel, C. —Introduction to Solid State Physicsl. Wiley, 2005.

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## **REFERENCES:**

1. Garcia, N. & Damask, A. —Physics for Computer Science Studentsll. Springer-Verlag, 2012.

2. Hanson, G.W. —Fundamentals of Nanoelectronicsll. Pearson Education, 2009.

3. Rogers, B., Adams, J. & Pennathur, S. —Nanotechnology: Understanding Small Systemsll. CRC Press, 2014.